## **Application Data Sheet**

#### **Application Information**

Application Type:: Regular

Subject Matter:: Utility

Title:: NONVOLATILE SEMICONDUCTOR MEMORY

DEVICE HAVING FERROELECTRIC

CAPACITORS

Attorney Docket Number:: 001701.00204

Request for Early Publication?:: NO

Request for Non-Publication?:: NO

Total Drawing Sheets:: 30

Small Entity?:: NO

Secrecy Order in Parent Appl.?:: NO

#### **Applicant Information**

Applicant Authority Type:: Inventor

Primary Citizenship Country:: Japan

Status:: Full Capacity

Given Name:: Daisaburo

Family Name:: Takashima

City of Residence:: Yokohama-shi

Country of Residence:: Japan

Street of mailing address:: c/o Kabushiki Kaisha Toshiba

1-1 Shibaura, 1-chome

City of mailing address:: Yokohama-shi

State or Province of mailing address::

Country of mailing address:: Japan

Postal or Zip Code of mailing address::

Correspondence Information

Correspondence Customer Number::

22907

**Representative Information** 

Representative Customer Number::

22907

## **Domestic Priority Information**

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application	Divisional of	10/607,301	06/27/03
	Divisional of	10/279,910	10/25/02
	Divisional of	09/902,168	07/11/01

## **Foreign Priority Information**

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2000-210474	07/11/00	Yes

# **Assignee Information**

Assignee name::

Kabushiki Kaisha Toshiba

City of mailing address::

Minato-Ku

Country of mailing address::

Japan